









CEP6060L

60V ▲ 17mΩ ▲ 52.4A ▲ Si MOSFET

SILICON Si MOSFET ▲ THT type
N-channel enhancement mode
UL94V-0 rated flame retardant epoxy
TO220-3L package

Super high dense cell density for extremely low R_{DS(ON)} **High power and current handling capability**

MAXIMUM RATINGS

Parameter (T _C = 25°C, unless otherwise noted)		Characteristics
Drain-Source Voltage	V _{DS}	60V
Gate-Source Voltage	V _{GS}	±16V
Continuous Drain Current at T _C = 25°C	I D	52.4A
Continuous Drain Current at T _C = 100°C	I _D	37A
Pulsed Drain Current Note 1	I _{DM} Note 5	210A
Maximum Power Dissipation at T _C = 25°C	P _D	120W
Power Dissipation Derating above 25°C	ΔP_D	0.8W/°C
Single Pulsed Avalanche Energy Note 4	E _{AS}	59.3mJ
Single Pulsed Avalanche Current Note 4	I _{AS}	25A
Operating and Storage Temperature Range	T _J , T _{STG}	-55°C to +175°C

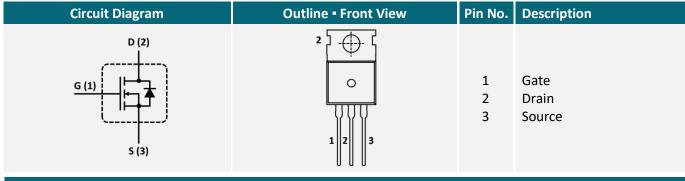
THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R _{TH_JC}	1.24°C/W
Thermal Resistance, Junction-to-Ambient	R _{TH JA}	62.5°C/W

APPLICATIONS

Battery Management Systems	DC/DC	DC	Industrial	Power
	Converter	Fan	Control	Switches
+4-				

PIN DESCRIPTION



MGT ▲ Manufacturer Group of Technology



ELECTRICAL CHARACTERISTICS ▲ T_C = 25°C, unless otherwise noted

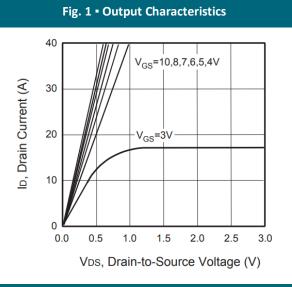
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	60			V
Zero Gate Voltage Drain Current	$V_{DS} = 60V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Gate Body Leakage Current, Forward	$V_{GS} = 16V$, $V_{DS} = 0V$	I _{GSSF}			100	nA
Gate Body Leakage Current, Reverse	$V_{GS} = -16V, V_{DS} = 0V$	I_{GSSR}			-100	nA
On Characteristics Note 2						
Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_{D} = 250 \mu A$	$V_{GS(th)}$	1	1.4	2	V
Static Drain-Source On-Resistance	$V_{GS} = 10V$, $I_D = 26.2A$	R _{DS(ON)}		17	21	mΩ
Static Drain-Source On-Resistance	$V_{GS} = 5V$, $I_D = 26.2A$	R _{DS(ON)}		20	25	mΩ
Dynamic Characteristics Note 3						
Input Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	C _{ISS}		1480		pF
Output Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	Coss		300		pF
Reverse Transfer Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	C _{RSS}		50		pF
Switching Characteristics Note 3						
Turn-On Delay Time	V_{DD} = 30V, V_{GS} = 10V, I_D = 48A, $R_{G(ext)}$ = 15 Ω	t _{D(ON)}		15		ns
Turn-On Rise Time	V_{DD} = 30V, V_{GS} = 10V, I_D = 48A, $R_{G(ext)}$ = 15 Ω	t_R		4.5		ns
Turn-Off Delay Time	V_{DD} = 30V, V_{GS} = 10V, I_D = 48A, $R_{G(ext)}$ = 15 Ω	t _{D(OFF)}		124		ns
Turn-Off Fall Time	V_{DD} = 30V, V_{GS} = 10V, I_D = 48A, $R_{G(ext)}$ = 15 Ω	t _F		22		ns
Total Gate Charge	$V_{DS} = 48V$, $V_{GS} = 10V$, $I_D = 48A$	Q_{G}		45		nC
Gate Source Charge	$V_{DS} = 48V$, $V_{GS} = 10V$, $I_D = 48A$	Q_{GS}		4.6		nC
Gate Drain Charge	$V_{DS} = 48V$, $V_{GS} = 10V$, $I_D = 48A$	Q_{GD}		9		nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Current		Is			52.4	А
Drain-Source Diode Forward Voltage Note 2	V _{GS} = 0V, I _S = 35A	V_{SD}		0.8	1.3	V

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: L = 0.19mH, I_{AS} = 25A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C.
- 5: Pulse width limited by safe operating area.



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE



T_J=1<u>25°C</u>

T_J=1<u>25°C</u>

O

25°C

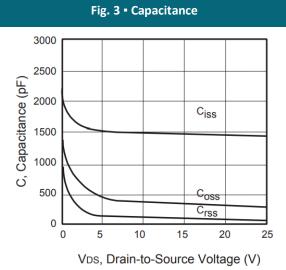
T_J=1<u>25°C</u>

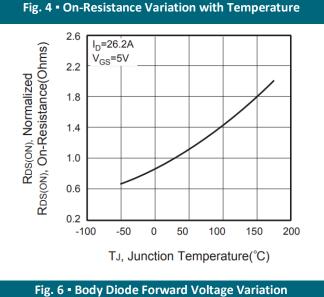
T_J=4

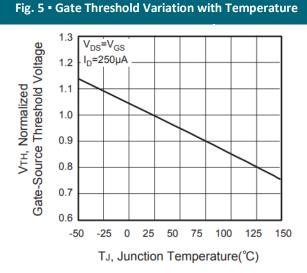
6

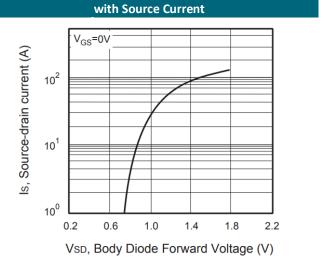
Vgs, Gate-to-Source Voltage (V)

Fig. 2 • Transfer Characteristics









MGT ▲ Manufacturer Group of Technology



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

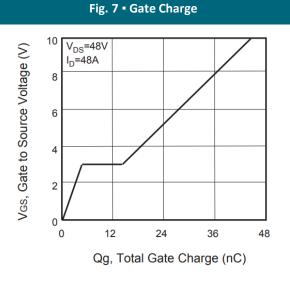


Fig. 8 • Maximum Safe Operating Area

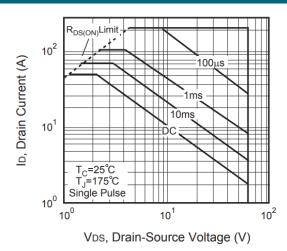
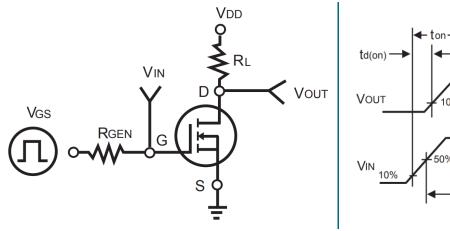


Fig. 9 • Switching Test Circuit

Fig. 10 • Switching Waveforms



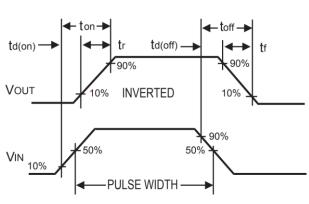
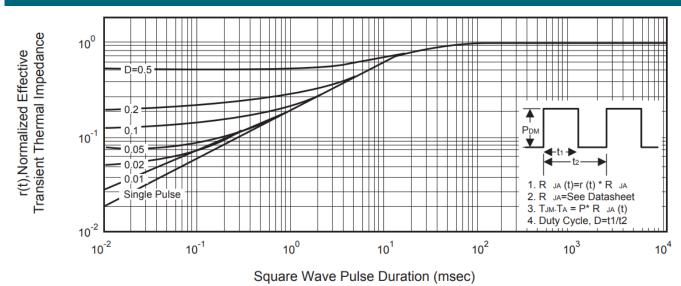


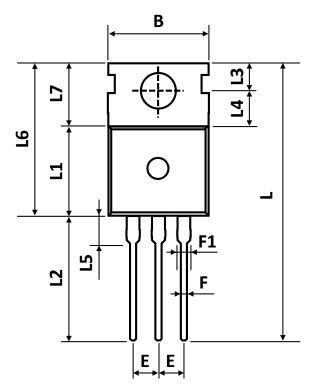
Fig. 11 - Normalized Thermal Transient Impedance Curve

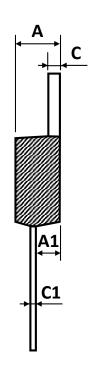


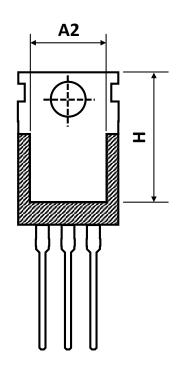
MGT A Manufacturer Group of Technolog



PACKAGE OUTLINE







Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
Α	4.43	4.53	4.63
A1	2.30	2.40	2.50
A2	7.70	7.90	8.10
В	9.80	10.00	10.20
С	1.25	1.30	1.40
C1	0.45	0.50	0.60
D	3.45	3.60	3.70
E	2.45	2.54	2.60
F	0.70	0.80	0.95
F1	1.15	1.33	1.50
L	26.80	28.80	30.80
L1	9.20	9.30	9.40
L2	12.80	13.10	13.40
L3	2.70	2.80	2.90
L4	3.50	3.70	3.80
L5	2.60	2.90	3.20
L6	15.40	15.80	16.20
L7	6.20	6.50	6.80
Н	12.95	13.25	13.55

ORDERING INFORMATION

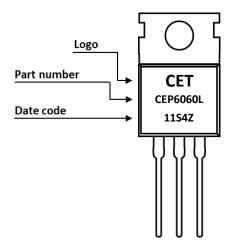
Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
CEP6060L	TO-220-3L	Tube	50pcs	1,000pcs	4,000pcs

MGT

Manufacturer Group of Technology

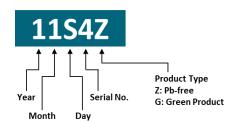


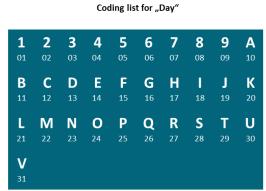
PART MARKING



DATE CODE

Example: 11S4Z

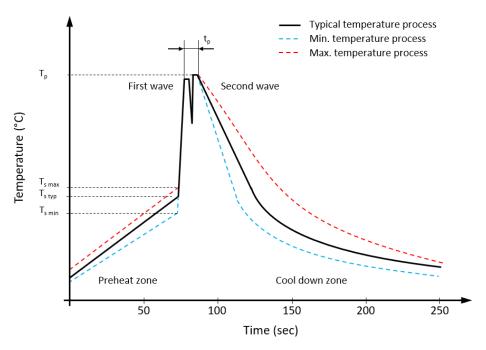








RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value ▲ Sn-Pb Assembly	Value ▲ Pb-free Assembly
Preheat temperature min.	$T_{s min}$	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	T _{s max}	130 °C	130 °C
Preheat time t_s from T_{smin} to T_{smax}	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t _p	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes



REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

DISCLAIMER

Except for the written expressed warranties, MGT does not implicitly, by assumption or whatever else, warrant, under-take, promise any other warranty or guaranty for any MGT product.

All information and technical specifications made available by MGT are for guidance only and we reserve the right to change or modify them without prior notice. Unless expressly stated in writing by MGT, we reject any guarantees, obligations, or warranties.

All MGT products with the technical specifications described are suitable for use in certain applications. Operating, production, storage and environmental conditions can have a massive influence on the parameters mentioned in the data sheets, which cause the performance to vary over time.

It is subject to the user's duty of care to design and validate his products in such a way that appropriate measures are taken, such as protective circuits or redundant systems to ensure the safety standards required in the application.

MGT components are not designed or rated for use in life support, rescue, safety critical, military, or aerospace applications where failure or malfunction could result in property or environmental damage, serious injury or death. In the aforementioned cases, please contact us before using MGT products.

In principle, we reserve all rights and MGT's general terms and conditions apply. You can find them on our website www.mgt.co.com.